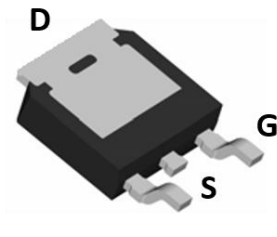
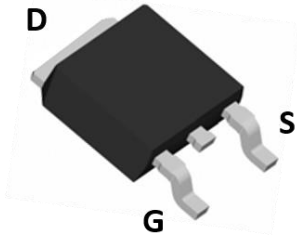
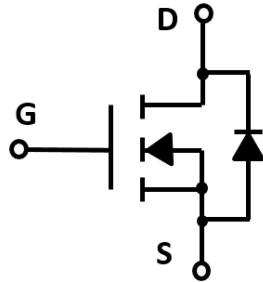


N-Channel Enhancement Mode Field Effect Transistor



TO-252



Product Summary

- V_{DS} 60V
- I_D 80A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) <8 mohm
- $R_{DS(ON)}$ (at $V_{GS}=4.5V$) <11 mohm
- 100% UIS Tested
- 100% ∇V_{DS} Tested

General Description

- Split Gate Trench MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$

Applications

- DC-DC Converters
- Power management functions
- Industrial and Motor Drive applications

■ Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	V_{DS}	60	V
Gate-source Voltage	V_{GS}	± 20	V
Drain Current	I_D	$T_C=25^\circ\text{C}$	A
		$T_C=100^\circ\text{C}$	
Pulsed Drain Current ^A	I_{DM}	240	A
Avalanche energy ^B	E_{AS}	225	mJ
Total Power Dissipation	P_D	$T_C=25^\circ\text{C}$	W
		$T_C=100^\circ\text{C}$	
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	1.76	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{STG}	$-55 \sim +175$	$^\circ\text{C}$

■ Ordering Information (Example)

PREFERED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJD80G06A	F1	YJD80G06A	2500	2500	25000	13" reel



YJD80G06A

■ Electrical Characteristics (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Conditions		Min	Typ	Max	Units
Static Parameter							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =250μA		60			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	T _J =25℃			1	μA
			T _J =55℃			5	
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} =0V				±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =250μA		1.2	1.7	2.2	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} = 10V, I _D =20A			6.6	8	mΩ
		V _{GS} = 4.5V, I _D =10A			9.3	11	
Diode Forward Voltage	V _{SD}	I _S =20A,V _{GS} =0V			0.8	1.2	V
Maximum Body-Diode Continuous Current	I _S					80	A
Dynamic Parameters							
Input Capacitance	C _{iss}	V _{DS} =30V,V _{GS} =0V,f=1MHZ			1990		pF
Output Capacitance	C _{oss}				470		
Reverse Transfer Capacitance	C _{rss}				14		
Switching Parameters							
Total Gate Charge	Q _g	V _{GS} =10V,V _{DS} =30V,I _D =20A			31		nC
Gate-Source Charge	Q _{gs}				6		
Gate-Drain Charge	Q _{gd}				5		
Reverse Recovery Chrage	Q _{rr}	I _F =20A, di/dt=500A/us			17		
Reverse Recovery Time	t _{rr}				58		
Turn-on Delay Time	t _{D(on)}	V _{GS} =10V,V _{DD} =30V,R _L =1Ω R _{GEN} =3Ω			10		ns
Turn-on Rise Time	t _r				5		
Turn-off Delay Time	t _{D(off)}				30		
Turn-off fall Time	t _f				8		

A. Pulse Test: Pulse Width≤300us, Duty cycle ≤2%.

B. T_J=25℃, V_{DD}=30V, V_G=10V, L=0.5mH, R_g=25 Ω



■ Typical Performance Characteristics

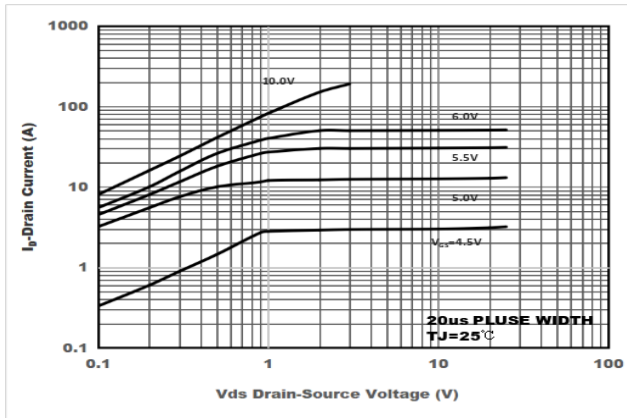


Figure1. Output Characteristics

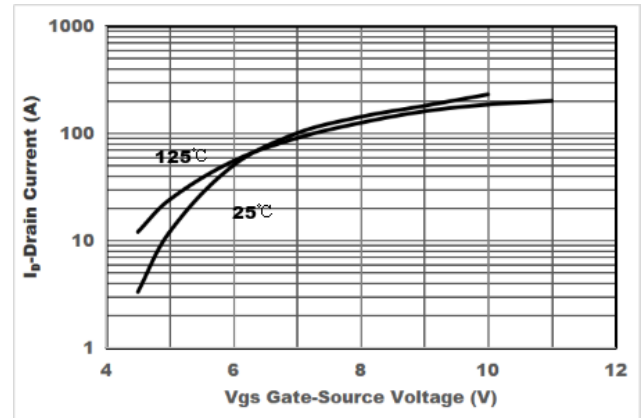


Figure2. Transfer Characteristics

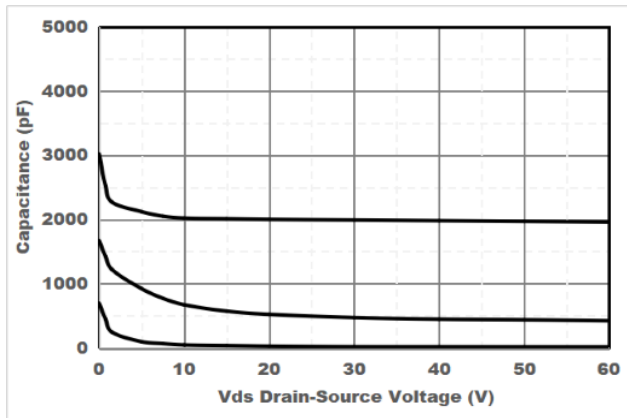


Figure3. Capacitance Characteristics

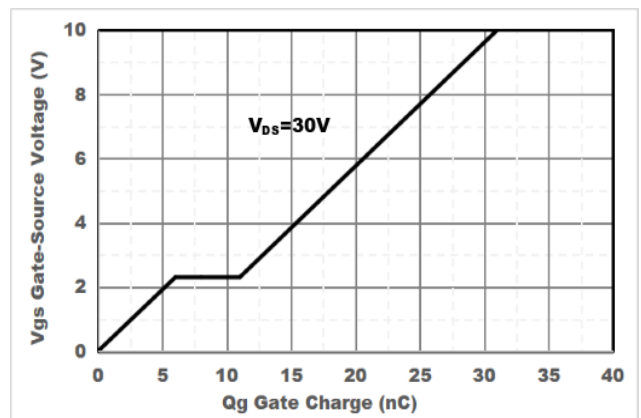


Figure4. Gate Charge

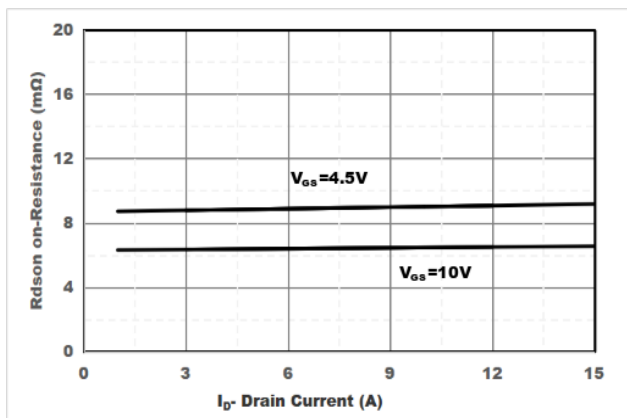


Figure5. Drain-Source on Resistance

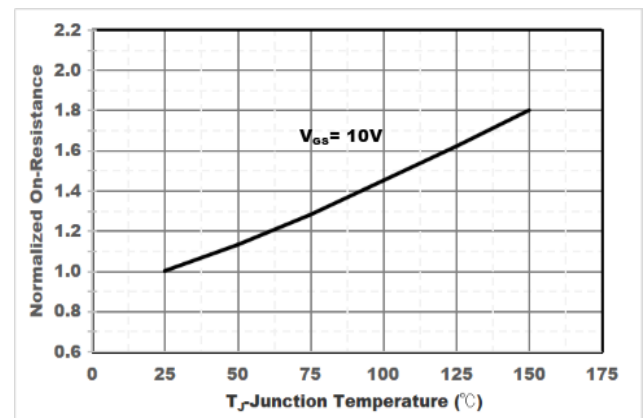


Figure6. Drain-Source on Resistance

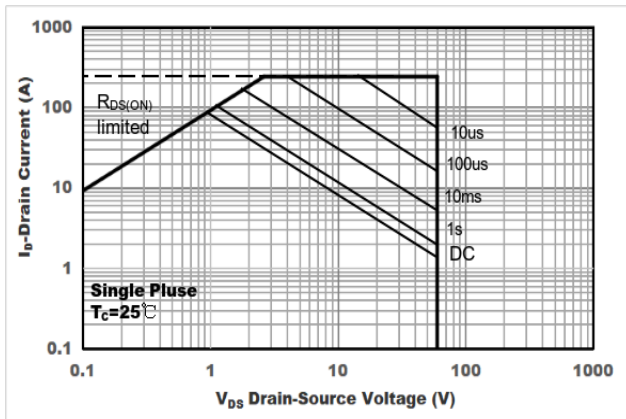


Figure7. Safe Operation Area

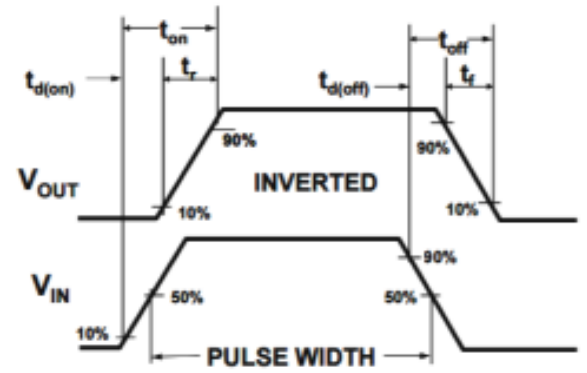
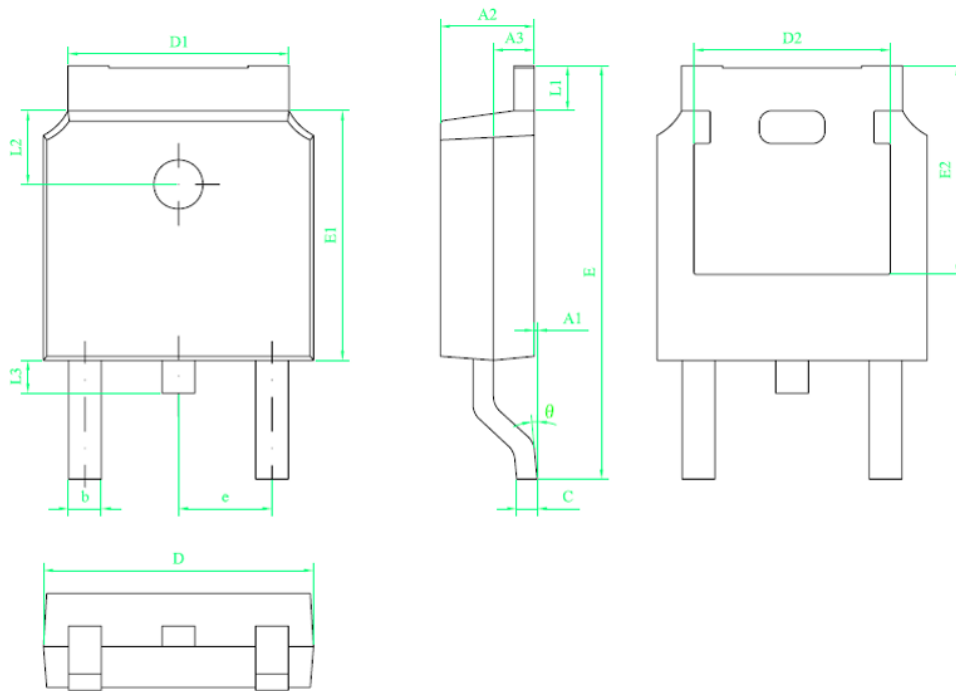


Figure8. Switching wave



YJD80G06A

■ TO-252 Package information



符 号	尺 寸		
	min	nom	max
A1	0	----	0.10
A2	2.20	2.30	2.40
A3	0.90	1.00	1.10
b	0.75	----	0.85
c	0.50	----	0.60
D	6.50	6.60	6.70
D1	5.30	5.40	5.50
D2	4.70	4.80	4.90
E	9.90	10.10	10.30
E1	6.00	6.10	6.20
E2	5.20	5.30	5.40
e	2.20	2.286	2.40
L1	0.90	----	1.25
L2	1.70	1.80	1.90
L3	0.60	0.80	1.00
θ	0°	----	8°

技术要求:

1. 树脂体不应有崩裂、缺损等缺陷;
2. 树脂上下部X、Y方向偏差不得超过0.20;
3. 胶体两端留胶总宽度和宽度不超过0.50;
4. 所有单位为mm;



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The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

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